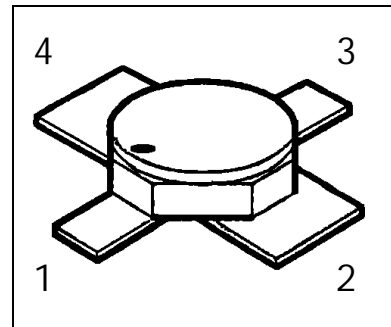


## HiRel NPN Silicon RF Transistor

- **HiRel Discrete and Microwave Semiconductor**
- For low noise, high-gain amplifiers up to 2GHz.
- For linear broadband amplifiers
- Hermetically sealed microwave package
- $f_T = 6,5$  GHz  
F = 3 dB at 2 GHz
-  **ESA Space Qualification Expected 1998**  
ESA/SCC Detail Spec. No.: 5611/006  
Type Variant No. 07 (tbc.)



**ESD:** Electrostatic discharge sensitive device, observe handling precautions!

Type	Marking	Ordering Code	Pin Configuration				Package
			C	E	B	E	
BFY196 (ql)	-	see below	C	E	B	E	Micro-X1

(ql) Quality Level:	P: Professional Quality,	Ordering Code:	Q62702F1684
	H: High Rel Quality,	Ordering Code:	on request
	S: Space Quality,	Ordering Code:	on request

(see order instructions for ordering example)

**Maximum Ratings**

Parameter	Symbol	Values	Unit
Collector-emitter voltage	$V_{CEO}$	12	V
Collector-emitter voltage, $V_{BE}=0$	$V_{CES}$	20	V
Collector-base voltage	$V_{CBO}$	20	V
Emitter-base voltage	$V_{EBO}$	2	V
Collector current	$I_C$	100	mA
Base current	$I_B$	12 <sup>1)</sup>	mA
Total power dissipation, $T_S \leq 105^\circ\text{C}$ <sup>2), 3)</sup>	$P_{tot}$	700	mW
Junction temperature	$T_j$	200	$^\circ\text{C}$
Operating temperature range	$T_{op}$	-65...+200	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-65...+200	$^\circ\text{C}$

**Thermal Resistance**

Junction-soldering point <sup>3)</sup>	$R_{thJS}$	< 135	K/W
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**Notes.:**

- 1) The maximum permissible base current for  $V_{FBE}$  measurements is 50mA (spot-measurement duration < 1s)
- 2) At  $T_S = +105^\circ\text{C}$ . For  $T_S > +105^\circ\text{C}$  derating is required.
- 3)  $T_S$  is measured on the collector lead at the soldering point to the pcb.

**Electrical Characteristics**

 at  $T_A=25^\circ\text{C}$ ; unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**DC Characteristics**

Collector-base cutoff current $V_{CB} = 20\text{ V}, I_E = 0$	$I_{CBO}$	-	-	100	$\mu\text{A}$
Collector-emitter cutoff current $V_{CE} = 12\text{ V}, I_B = 1\mu\text{A}$ <sup>1.)</sup>	$I_{CEX}$	-	-	1000	$\mu\text{A}$
Collector-base cutoff current $V_{CB} = 10\text{ V}, I_E = 0$	$I_{CBO}$	-	-	50	nA
Emitter base cutoff current $V_{EB} = 2\text{ V}, I_C = 0$	$I_{EBO}$	-	-	25	$\mu\text{A}$
Emitter base cutoff current $V_{EB} = 1\text{ V}, I_C = 0$	$I_{EBO}$	-	-	0.5	$\mu\text{A}$

**Notes:**

- 1.) This Test assures  $V(BR)_{CE0} > 12\text{V}$

**Electrical Characteristics (continued)**

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Base-Emitter forward voltage $I_E = 50 \text{ mA}, I_C = 0$	$V_{FBE}$	-	-	1	V
DC current gain $I_C = 50 \text{ mA}, V_{CE} = 8 \text{ V}$	$h_{FE}$	50	100	175	-
<b>AC Characteristics</b>					
Transition frequency $I_C = 70 \text{ mA}, V_{CE} = 5 \text{ V}, f = 500 \text{ MHz}$	$f_T$	6	6.5	-	GHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, V_{BE} = v_{be} = 0, f = 1 \text{ MHz}$	$C_{CB}$	-	1	1.3	pF
Collector-emitter capacitance $V_{CE} = 10 \text{ V}, V_{BE} = v_{be} = 0, f = 1 \text{ MHz}$	$C_{CE}$	-	0.44	-	pF
Emitter-base capacitance $V_{EB} = 0.5 \text{ V}, V_{CB} = v_{cb} = 0, f = 1 \text{ MHz}$	$C_{EB}$	-	3,6	4,3	pF
Noise Figure $I_C = 20 \text{ mA}, V_{CE} = 5 \text{ V}, f = 2 \text{ GHz},$ $Z_S = Z_{Sopt}$	F	-	3	3.5	dB
Power gain $I_C = 70 \text{ mA}, V_{CE} = 5 \text{ V}, f = 2 \text{ GHz}$ $Z_S = Z_{Sopt}, Z_L = Z_{Lopt}$	$G_{ma}^{1)}$	10	11	-	dB
Transducer gain $I_C = 70 \text{ mA}, V_{CE} = 5 \text{ V}, f = 2 \text{ GHz}$ $Z_S = Z_L = 50 \Omega$	$ S_{21e} ^2$	4	5	-	dB
Output Power $I_C = 80 \text{ mA}, V_{CE} = 5 \text{ V}, f = 2 \text{ GHz},$ $P_{IN} = 15 \text{ dBm}, Z_S = Z_L = 50 \Omega$	$P_{OUT}$	18.5	19.5	-	dBm

**Notes.:**

$$1) \quad G_{ma} = \left| \frac{S_{21}}{S_{12}} \right| (k - \sqrt{k^2 - 1}), \quad G_{ms} = \left| \frac{S_{21}}{S_{12}} \right|$$

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**Order Instructions:**

Full type variant including quality level must be specified by the orderer. For *HiRel* Discrete and Microwave Semiconductors the ordering code specifies device family and quality level.

**Ordering Form:**

Ordering Code: Q.....  
BFY196 (ql)  
(ql): Quality Level

**Ordering Example:**

Ordering Code: Q62702F1684  
BFY196 P  
For BFY196 in Professional Quality Level

**Further Informations:**

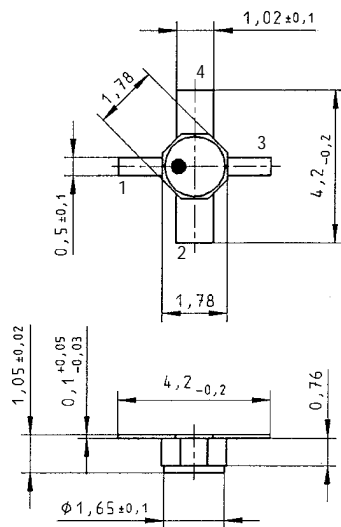
See our WWW-Pages:

- Discrete and RF-Semiconductors (Small Signal Semiconductors)  
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- *HiRel* Discrete and Microwave Semiconductors  
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## Micro-X1 Package



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